

MT3S07T

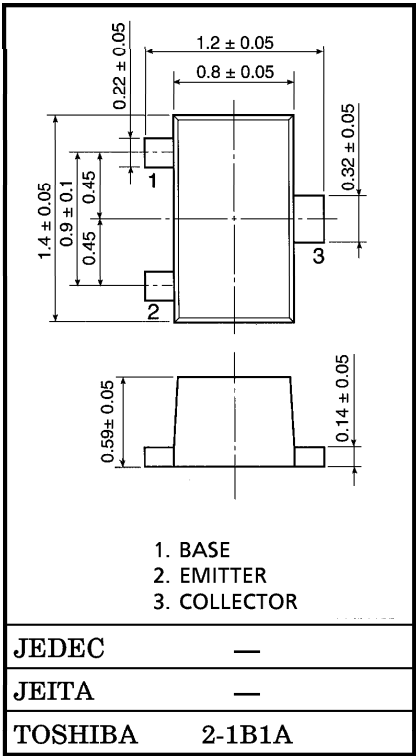
VHF~UHF BAND LOW NOISE AMPLIFIER APPLICATIONS

Unit in mm

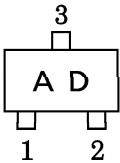
- Low Noise Figure : NF = 1.5 dB
(V_{CE} = 3 V, I_C = 5 mA, f = 2 GHz)
- High Gain : |S_{21e}|² = 9.5 dB
(V_{CE} = 3 V, I_C = 15 mA, f = 2 GHz)

MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	V _{CBO}	10	V
Collector-Emitter Voltage	V _{CEO}	5	V
Emitter-Base Voltage	V _{EBO}	1.5	V
Collector Current	I _C	25	mA
Base Current	I _B	10	mA
Collector Power Dissipation	P _C	100	mW
Junction Temperature	T _j	125	°C
Storage Temperature Range	T _{stg}	−55~125	°C



MARKING



MICROWAVE CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Transition Frequency	f _T	V _{CE} = 3 V, I _C = 10 mA	10	12	—	GHz
Insertion Gain	S _{21e} ² (1)	V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	—	7.5	—	dB
	S _{21e} ² (2)	V _{CE} = 3 V, I _C = 15 mA, f = 2 GHz	6.5	9.5	—	
Noise Figure	NF (1)	V _{CE} = 1 V, I _C = 5 mA, f = 2 GHz	—	1.6	3	dB
	NF (2)	V _{CE} = 3 V, I _C = 5 mA, f = 2 GHz	—	1.5	3	

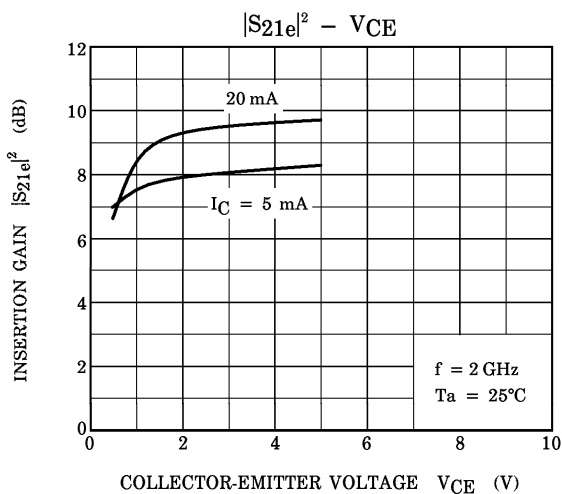
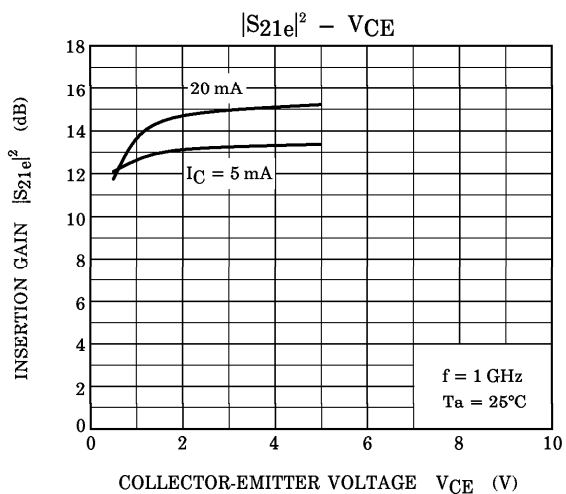
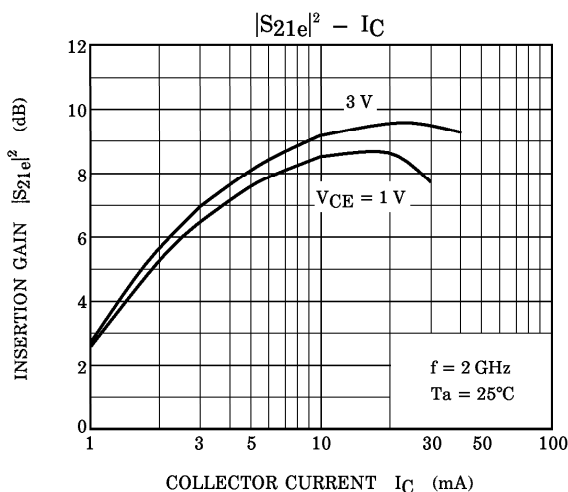
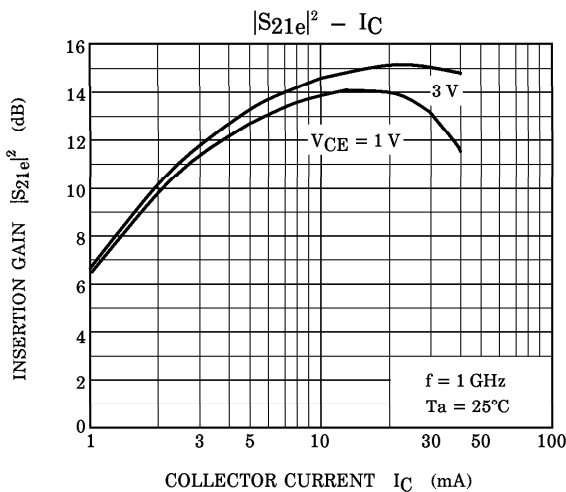
ELECTRICAL CHARACTERISTICS (Ta = 25°C)

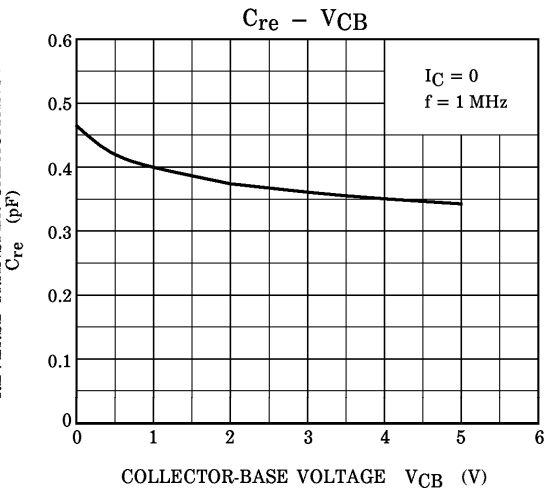
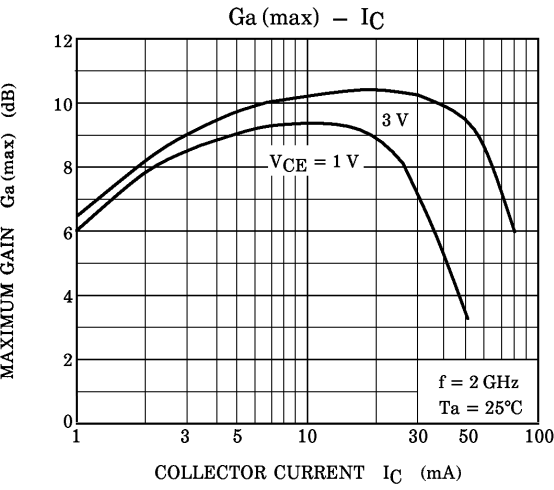
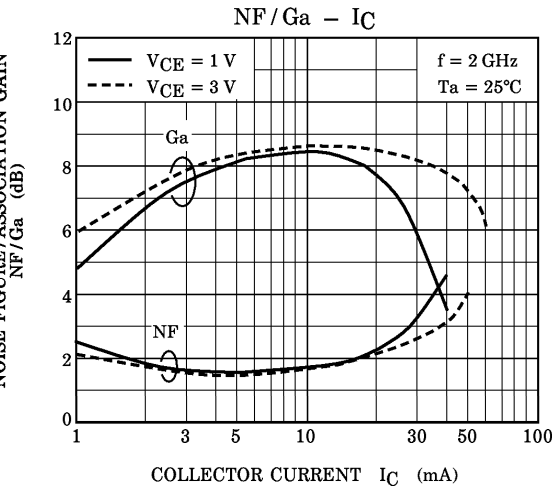
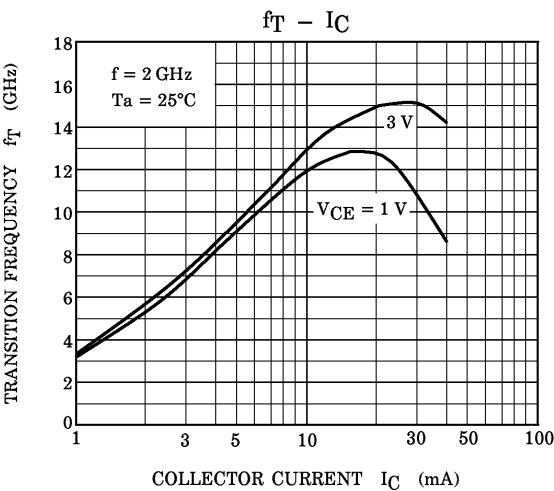
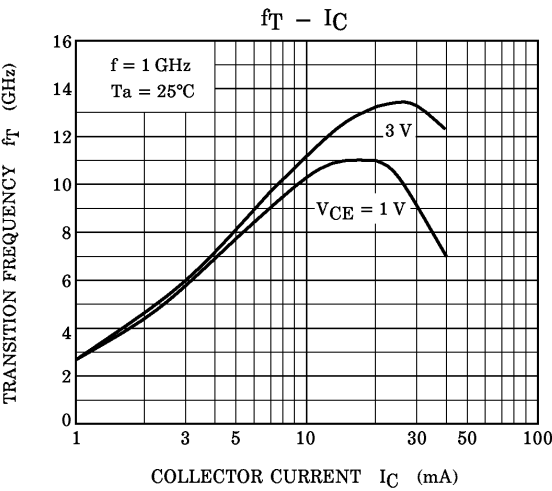
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	ICBO	V _{CB} = 5 V, I _E = 0	—	—	0.1	μA
Emitter Cut-off Current	IEBO	V _{EB} = 1 V, I _C = 0	—	—	1	μA
DC Current Gain	h _{FE}	V _{CE} = 1 V, I _C = 5 mA	70	—	140	—
Reverse Transfer Capacitance	C _{re}	V _{CB} = 1 V, I _E = 0, f = 1 MHz (Note)	—	0.4	0.85	pF

(Note) : C_{re} is measured by 3 terminal method with capacitance bridge.

CAUTION

This device electrostatic sensitivity. Please handle with caution.





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